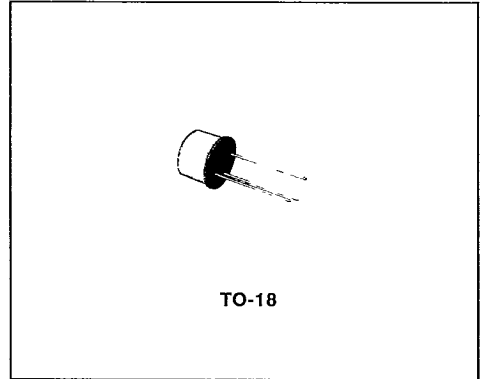
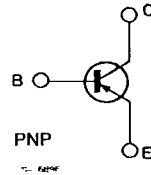


**DESCRIPTION**

The BCY70, BCY71 and BCY72 are silicon planar epitaxial PNP transistors in Jedec TO-18 metal case.

**INTERNAL SCHEMATIC DIAGRAM****ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value			Unit
		BCY70	BCY71	BCY72	
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	- 50	- 45	- 25	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	- 40	- 45	- 25	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	- 5			V
$I_{CM}$	Collector Peak Current	- 200			mA
$P_{tot}$	Total Power Dissipation at $T_{amb} \leq 25^\circ\text{C}$	350			mW
$T_{stg}, T_J$	Storage and Junction Temperature	- 65 to 200			$^\circ\text{C}$

\* Pulsed : pulse duration = 300  $\mu\text{s}$ , duty cycle = 1 %.

HERMAL DATA

$R_{th j-case}$	Thermal Resistance Junction-case	Max	150	$^{\circ}C/W$
$R_{th j-amb}$	Thermal Resistance Junction-ambient	Max	500	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25^{\circ}C$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector Cutoff Current ( $V_{BE} = 0$ )	For <b>BCY70</b> $V_{CE} = -20 V$ $V_{CE} = -50 V$ For <b>BCY71</b> $V_{CB} = -20 V$ $V_{CB} = -45 V$ For <b>BCY72</b> $V_{CB} = -20 V$ $V_{CB} = -25 V$			-10 -500 -100 -10 -100 -10	nA nA nA $\mu A$ nA $\mu A$
$I_{EBO}$	Emitter cutoff Current ( $I_C = 0$ )	$V_{EB} = -5 V$			-10	$\mu A$
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = -10 mA$ $I_B = -1 mA$ $I_C = -50 mA$ $I_B = -5 mA$			-0.25 -0.5	V V
$V_{BE(sat)}^*$	Base-Emitter Saturation Voltage	$I_C = -10 mA$ $I_B = -1 mA$ For <b>BCY70</b> and <b>BCY71</b> Only $I_C = -50 mA$ $I_B = -5 mA$	-0.6		-0.9 -1.2	V V
$h_{FE}^*$	DC Current Gain	For <b>BCY70</b> $I_C = -0.1 mA$ $V_{CE} = -1 V$ $I_C = -1 mA$ $V_{CE} = -1 V$ $I_C = -10 mA$ $V_{CE} = -1 V$ $I_C = -50 mA$ $V_{CE} = -1 V$ For <b>BCY71</b> $I_C = -0.01 mA$ $V_{CE} = -1 V$ $I_C = -0.1 mA$ $V_{CE} = -1 V$ $I_C = -1 mA$ $V_{CE} = -1 V$ $I_C = -10 mA$ $V_{CE} = -1 V$ $I_C = -50 mA$ $V_{CE} = -1 V$ For <b>BCY72</b> $I_C = -1 mA$ $V_{CE} = -1 V$ $I_C = -10 mA$ $V_{CE} = -1 V$	40 45 50 15	60	600	
$h_{fe}$	Small Signal Current Gain (for <b>BCY71</b> only)	$I_C = -1 mA$ $V_{CE} = -10 V$ $f = 1 kHz$	100		400	
$f_T$	Transition Frequency	$I_C = -0.1 mA$ $V_{CE} = -20 V$ $f = 10.7 MHz$ For <b>BCY71</b> $I_C = -10 mA$ $V_{CE} = -20 V$ $f = 100 MHz$ For <b>BCY70</b> For <b>BCY70</b> and <b>BCY72</b>	15 250 200			MHz MHz MHz
$C_{EBO}$	Emitter-base Capacitance	$I_C = 0$ $V_{EB} = -1 V$ $f = 1 MHz$			8	pF
$C_{CBO}$	Collector-base Capacitance	$I_E = 0$ $V_{CB} = -10 V$ $f = 1 MHz$			6	pF

\* Pulsed : pulse duration = 300  $\mu s$ , duty cycle = 1 %.

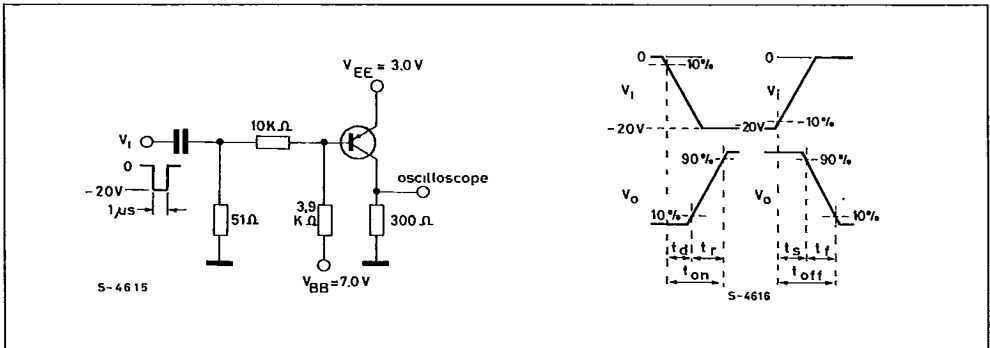
ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
NF	Noise Figure	$I_C = -0.1 \text{ mA}$ $V_{CE} = -5 \text{ V}$ $R_g = 2 \text{ k}\Omega$ $f = 10 \text{ to } 10\,000 \text{ Hz}$ For <b>BCY70</b> and <b>BCY72</b> for <b>BCY71</b>			6 2	dB dB
$h_{ie}$	Input Impedance (for <b>BCY71</b> only)	$I_C = -1 \text{ mA}$ $V_{CE} = -10 \text{ V}$ $f = 1 \text{ kHz}$	2		12	$\text{k}\Omega$
$h_{re}$	Reverse Voltage Ratio (for <b>BCY71</b> only)	$I_C = -1 \text{ mA}$ $V_{CE} = -10 \text{ V}$ $f = 1 \text{ kHz}$			$20 \times 10^{-4}$	
$h_{oe}$	Output Admittance (for <b>BCY71</b> only)	$I_C = -1 \text{ mA}$ $V_{CE} = -10 \text{ V}$ $f = 1 \text{ kHz}$	10		60	$\mu\text{S}$
$t_d$	Delay Time (for <b>BCY70</b> and <b>BCY72</b> only)	$I_C = -10 \text{ mA}$ $V_{EE} = 3 \text{ V}$ $I_{B1} = -1 \text{ mA}$		23	35	ns
$t_r$	Rise Time (for <b>BCY70</b> and <b>BCY72</b> only)	$I_C = -10 \text{ mA}$ $V_{EE} = 3 \text{ V}$ $I_{B1} = -1 \text{ mA}$		25	35	ns
$t_s$	Storage Time (for <b>BCY70</b> and <b>BCY72</b> only)	$I_C = -10 \text{ mA}$ $V_{EE} = 3 \text{ V}$ $I_{B1} = -I_{B2} = -1 \text{ mA}$		270	350	ns
$t_f$	Fall Time (for <b>BCY70</b> and <b>BCY72</b> only)	$I_C = -10 \text{ mA}$ $V_{EE} = 3 \text{ V}$ $I_{B1} = -I_{B2} = -1 \text{ mA}$		50	80	ns
$t_{on}$	Turn-on Time (for <b>BCY70</b> and <b>BCY72</b> only)	$I_C = -10 \text{ mA}$ $V_{EE} = 3 \text{ V}$ $I_{B1} = -1 \text{ mA}$		48	65	ns
$t_{off}$	Turn-off Time (for <b>BCY70</b> and <b>BCY72</b> only)	$I_C = -10 \text{ mA}$ $V_{EE} = 3 \text{ V}$ $I_{B1} = -I_{B2} = -1 \text{ mA}$		320	420	ns

\* Pulsed : pulse duration = 300  $\mu\text{s}$ , duty cycle = 1 %.

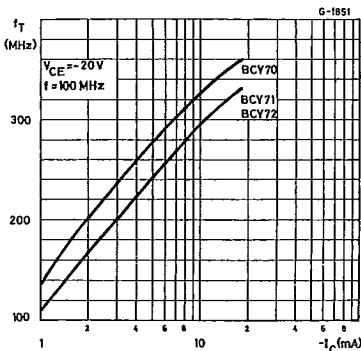
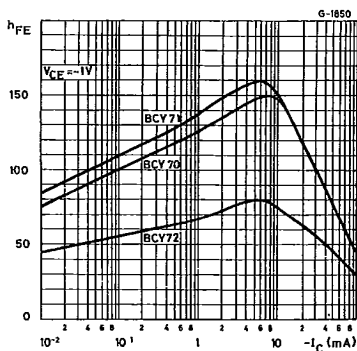
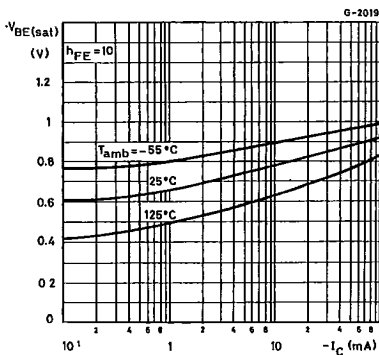
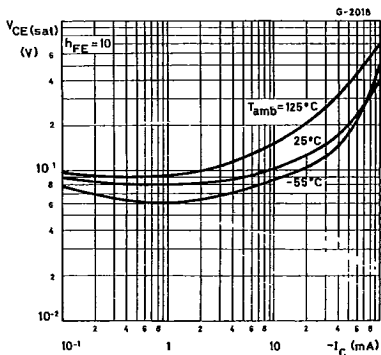
TEST CIRCUIT

Test Circuit for Switching Times.



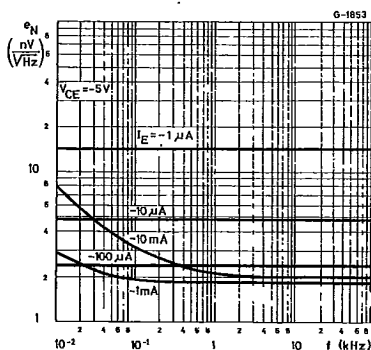
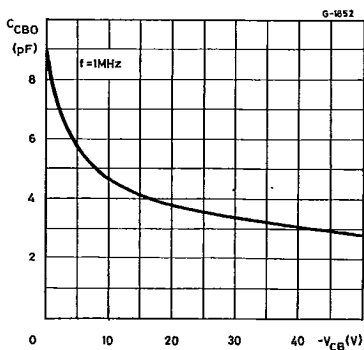
Collector-emitter Saturation Voltage.

Base-emitter Saturation Voltage.



Collector-base Capacitance.

Equivalent Input Noise Voltage (for BCY71 only).



SGS-THOMSON

T-27-09

Equivalent Input Noise Current (for BCY71 only).

Contours of Constant White Noise Figure (for BCY71 only).

